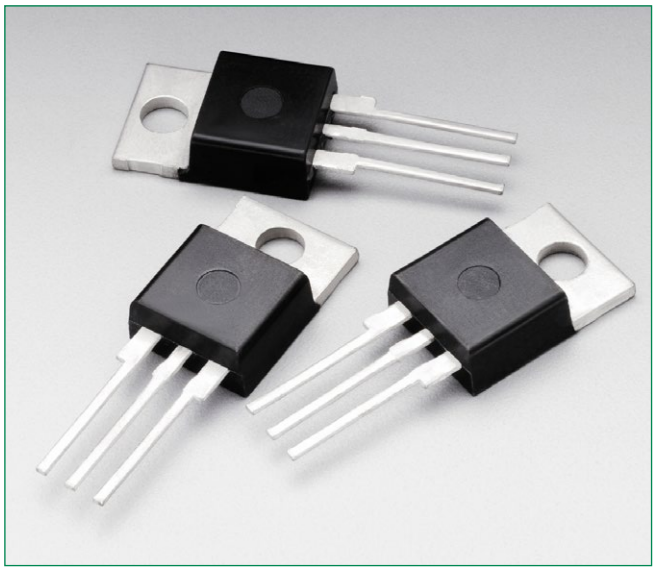
MAC4DSM, MAC4DSN



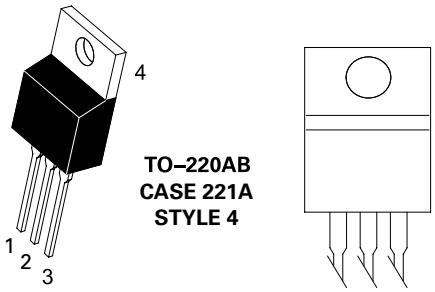
Description

Designed for high volume, low cost, industrial and consumer applications such as motor control; process control; temperature, light and speed control.

Features

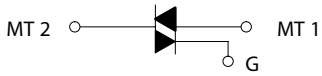
- Small Size Surface Mount DPAK Package
- Passivated Die for Reliability and Uniformity
- Blocking Voltage to 800 V
- On–State Current Rating of 4.0 A RMS at 108°C
- Low IGT – 10 mA Maximum in 3 Quadrants
- High Immunity to dv/dt – 50 V/μs at 125°C
- Epoxy Meets UL 94 V–0 @ 0.125 in
- ESD Ratings: Human Body Model, 3B > 8000 V Machine Model, C > 400 V
- Pb–Free Packages are Available

Pin Out



TO–220AB
CASE 221A
STYLE 4

Functional Diagram



Additional Information

Datasheet | **Resources** | **Samples**

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Revised: 07/11/19

Maximum Ratings (T_J = 25°C unless otherwise noted)

Rating		Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Note 1) (Gate Open, Sine Wave 50 to 60 Hz, T_J = -40° to 110°C)	MAC4DSM MAC4DSN	V_{DRM}, V_{RRM}	600 800	V
On-State RMS Current (Full Cycle Sine Wave, 60 Hz, T_C = 108°C)		$I_{T\ (RMS)}$	4.0	A
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T_C= 108°C)		I_{TSM}	40	A
Circuit Fusing Consideration (t = 8.3 msec)		I^2t	6.6	A^2sec
Peak Gate Current (Pulse Width ≤ 20 µsec, T_C= 108°C)		I_{GM}	4.0	A
Peak Gate Power (Pulse Width ≤ 10 µsec, T_C= 108°C)		P_{GM}	2.0	W
Peak Gate Voltage (Pulse Width ≤ 20 µsec, T_C= 108°C)		V_{GM}	5.0	V
Average Gate Power (t = 8.3 msec, T_C= 108°C)		$P_{G(AV)}$	1.0	W
Operating Junction Temperature Range		T_J	-40 to +125	°C
Storage Temperature Range		T_{stg}	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Thermal Characteristics

Rating		Symbol	Value	Unit
Thermal Resistance	Junction–to–Case (AC) Junction–to–Ambient Junction–to–Ambient (Note 2)	$R_{\theta JC}$ $R_{\theta JA}$ $R_{\theta JA}$	3.5 88 80	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8″ from case for 10 seconds (Note 3)		T_L	260	°C

2. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

3. 1/8" from case for 10 seconds.

Electrical Characteristics - OFF (T_J = 25°C unless otherwise noted ; Electricals apply in both directions)

Characteristic		Symbol	Min	Typ	Max	Unit
Peak Repetitive Blocking Current ($V_D = V_{DRM} = V_{RRM}$; Gate Open)	T_J = 25°C	I_{DRM}, I_{RRM}	-	-	0.01	mA
	T_J = 125°C		-	-	2.0	

Electrical Characteristics - ON (T_J = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic		Symbol	Min	Typ	Max	Unit
Peak On–State Voltage (Note 4) (I_{TM} = ±6.0 A)		V_{TM}	–	1.3	1.6	V
Gate Trigger Current (Continuous dc) (V_D = 12 V, R_L = 100 Ω)	MT2(+), G(+)	I_{GT}	2.9	4.0	10	mA
	MT2(+), G(–)		2.9	5.0	10	
	MT2(–), G(–)		2.9	7.0	10	
Holding Current (V_D = 12 V, Gate Open, Initiating Current = ±200 mA))		I_H	2.0	5.5	1.5	mA
Latching Current	MT2(+), G(+)	I_L	_	6.0	30	mA
	MT2(+), G(–)		_	10	30	
	MT2(–), G(–)		_	6.0	30	
Gate Trigger Voltage (Continuous dc) (V_D = 12 V, R_L = 100 Ω)	MT2(+), G(+)	V_{GT}	0.5	0.7	1.3	V
	MT2(+), G(–)		0.5	0.65	1.3	
	MT2(–), G(–)		0.5	0.7	1.3	
Gate Non–Trigger Voltage (T_J = 125°C) (V_D = 12 V, R_L = 100 Ω)	MT2(+), G(+)	V_{GD}	0.2	0.4	–	V
	MT2(+), G(–)		0.2	0.4	–	
	MT2(–), G(–)		0.2	0.4	–	

4. Indicates Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2%.

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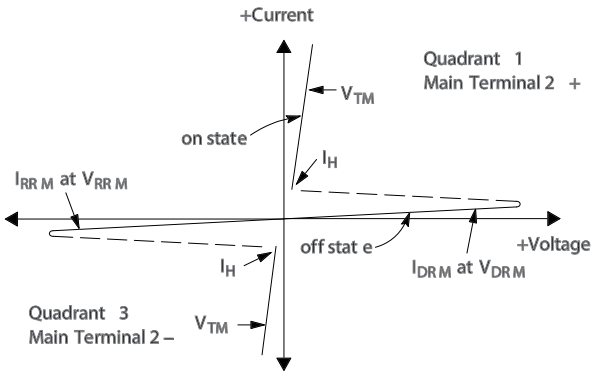
Dynamic Characteristics

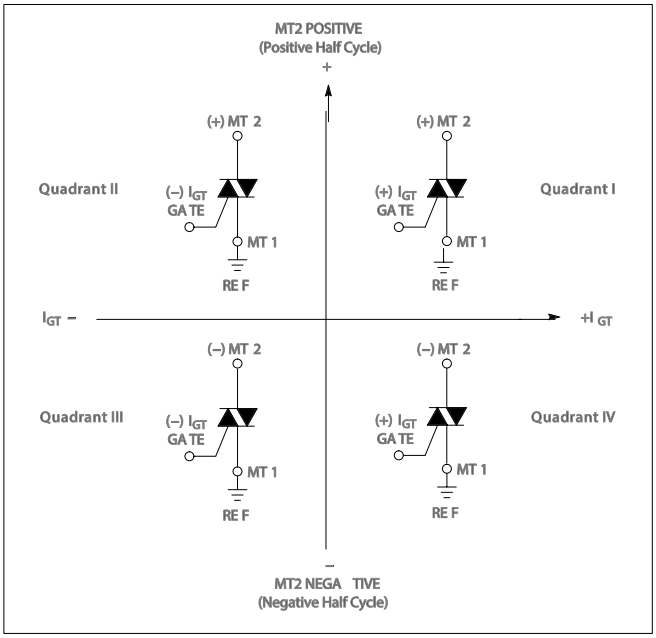
Characteristic	Symbol	Min	Typ	Max	Unit
Rate of Change of Commutating Current (V_D = 400 V, I_{TM} = 3.5 A, Commutating dv/dt = 10 V/µsec, Gate Open, T_J = 125°C, f = 500 Hz, CL = 5.0 µF, LL = 20 mH, No Snubber) See Figure 16	(dI/dt)c	3.0	4.0	–	A/ms
Critical Rate of Rise of Off-State Voltage (V_D = 0.67 x V_{DRM}, Exponential Waveform, Gate Open, T_J = 125°C)	dV/dt	50	175	–	V/µs

Voltage Current Characteristic of SCR

Symbol	Parameter
V_{DRM}	Peak Repetitive Forward Off State Voltage
I_{DRM}	Peak Forward Blocking Current
V_{RRM}	Peak Repetitive Reverse Off State Voltage
I_{RRM}	Peak Reverse Blocking Current
V_{TM}	Maximum On State Voltage
I_H	Holding Current



Quadrant Definitions for a Triac



All polarities are referenced to MT1.
With in–phase signals (using standard AC lines) quadrants I and III are used .

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Figure 1. Typical RMS Current Derating

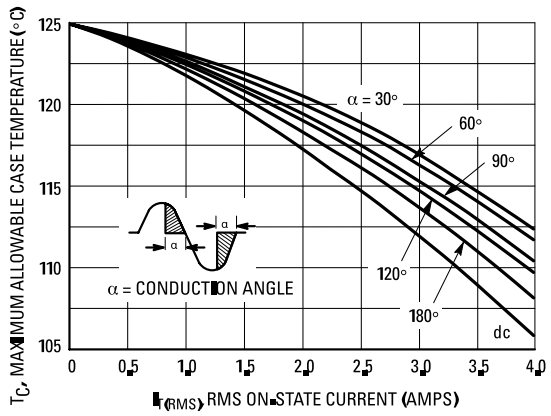

Figure 2. On-State Power Dissipation

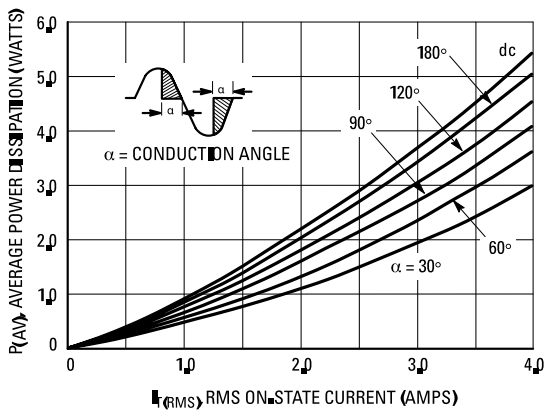

Figure 3. On–State Characteristics

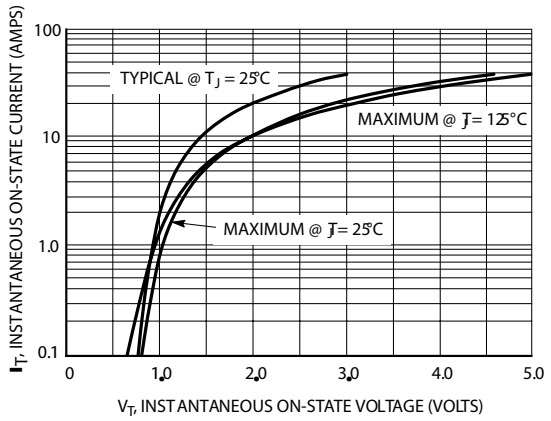

Figure 4. Transient Thermal Response

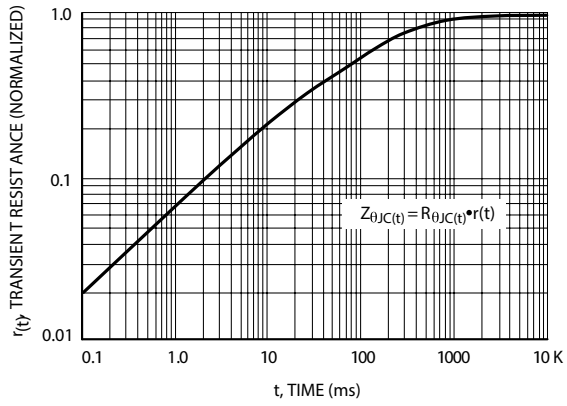

Figure 5. Typical Gate Trigger Current vs, Junction Temperature

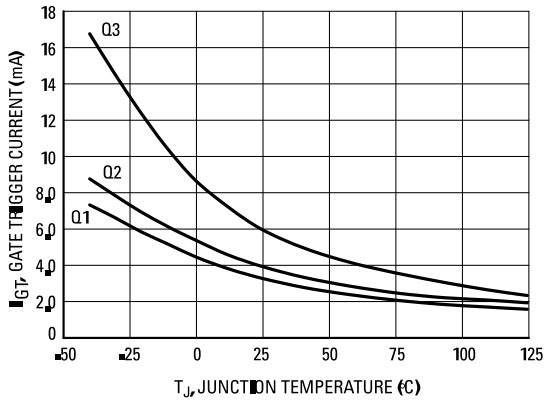

Figure 6. Typical Gate Trigger Voltage vs. Junction Temperature

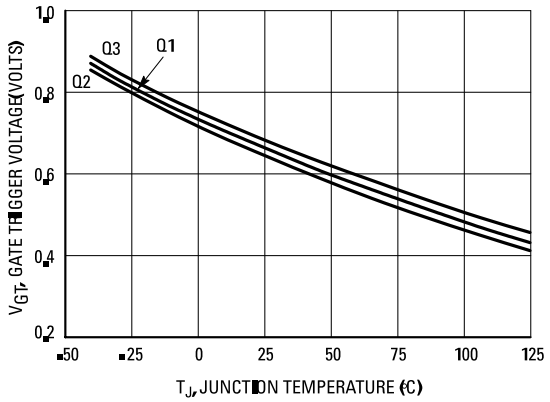

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Figure 7. Typical Holding Current vs. Junction Temperature

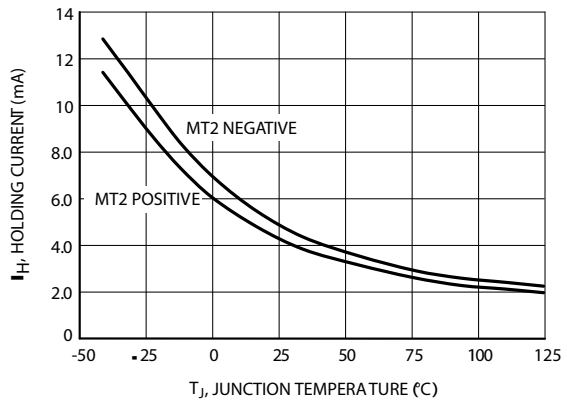

Figure 8. Typical Latching Current vs. Junction Temperature

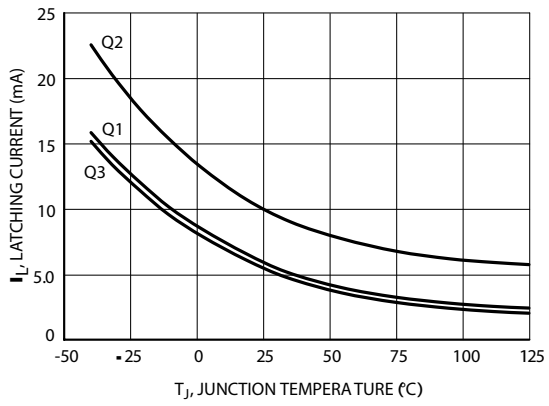

Figure 9. Exponential Static dv/dt vs. Gate–MT1 Resistance, MT2(+)

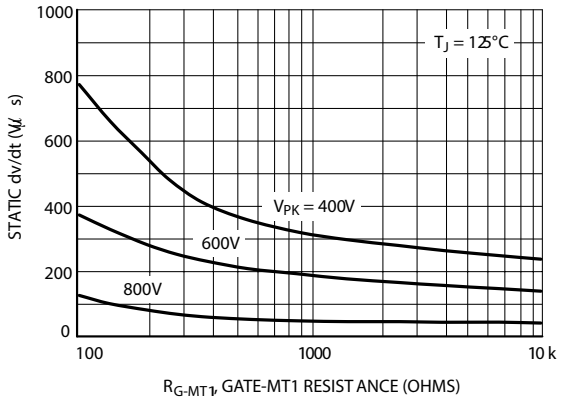

Figure 10. Exponential Static dv/dt vs. Gate–MT1 Resistance, MT2(-)

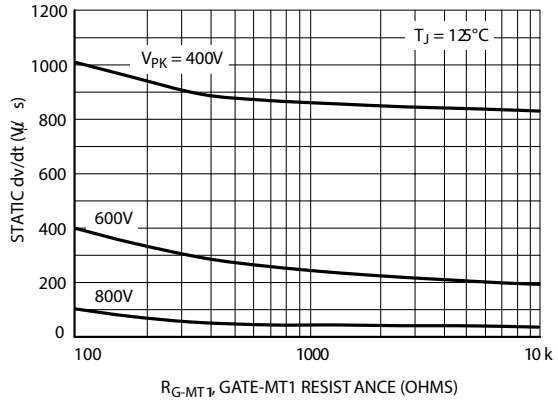

Figure 9. Exponential Static dv/dt vs. Gate–MT1 Resistance, MT2(+)

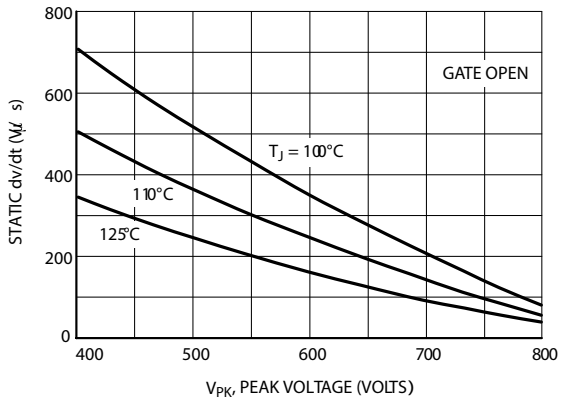

Figure 10. Exponential Static dv/dt vs. Gate–MT1 Resistance, MT2(-)

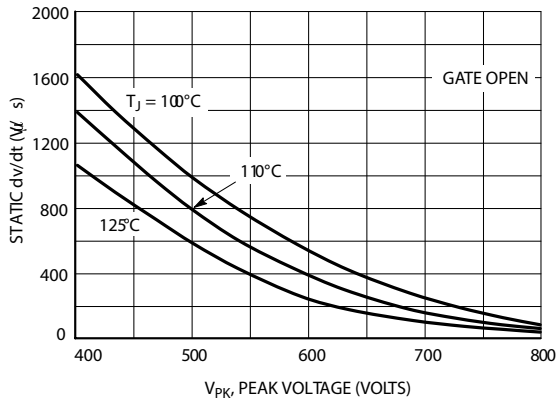

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Figure 13. Typical Holding Current vs. Junction Temperature

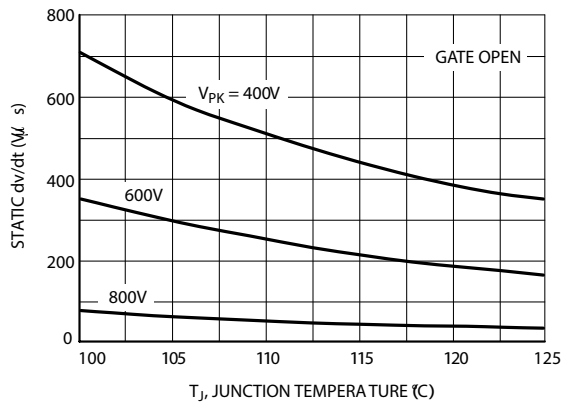


Figure 14. Typical Latching Current vs. Junction Temperature

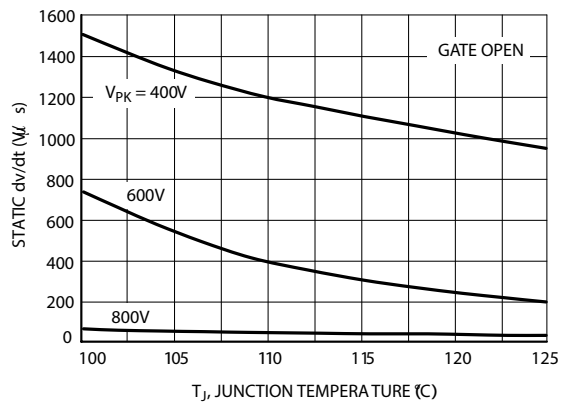


Figure 15. Typical Holding Current vs. Junction Temperature

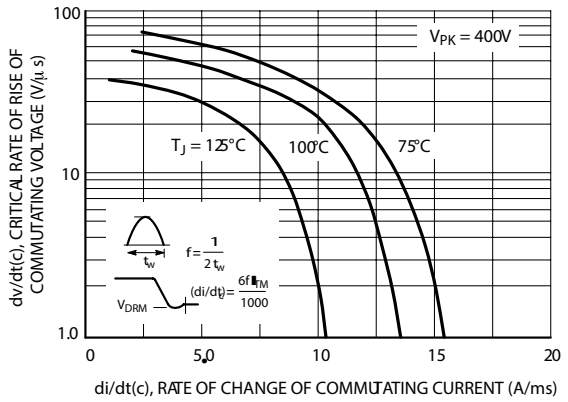
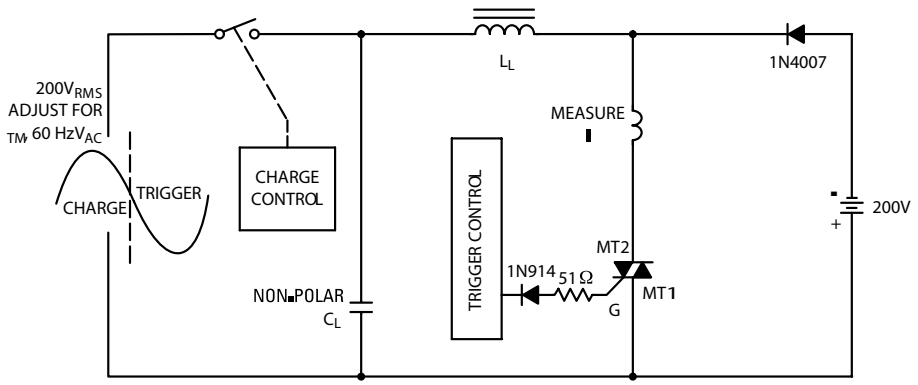


Figure 16. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current (di/dt)



Note: Component values are for verification of rated (di/dt)c. See AN1048 for additional information.

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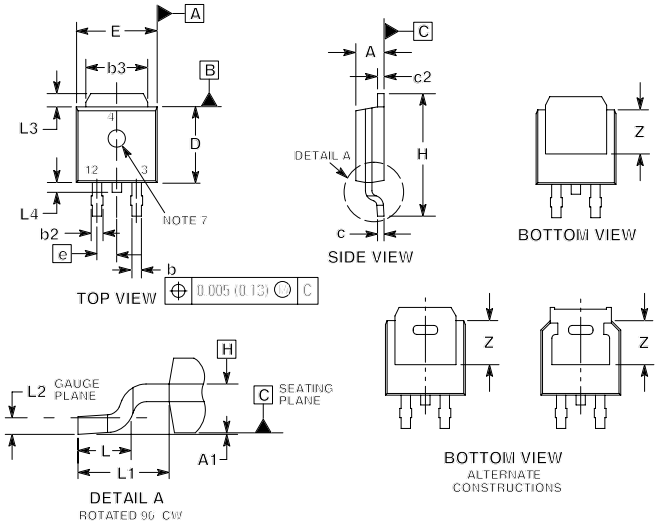
Dimensions

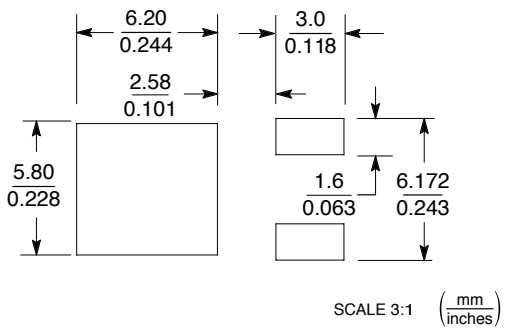


Dim	Inches		Millimeters	
	Min	Max	Min	Max
A	0.087	0.094	2.20	2.40
A1	0.000	0.005	0.00	0.12
b	0.022	0.030	0.55	0.75
b2	0.026	0.033	0.65	0.85
b3	0.209	0.217	5.30	5.50
c	0.019	0.023	0.49	0.59
c2	0.019	0.023	0.49	0.59
D	0.213	0.224	5.40	5.70
E	0.252	0.260	6.40	6.60
e	0.091		2.30	
H	0.374	0.406	9.50	10.30
L	0.058	0.070	1.47	1.78
L1	0.114		2.90	
L2	0.019	0.023	0.49	0.59
L3	0.053	0.065	1.35	1.65
L4	0.028	0.039	0.70	1.00
Z	0.154	-	3.90	-

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

STYLE 6:
PIN 1. MT1
2. MT2
3. GATE
4. MT2

Soldering Footprint



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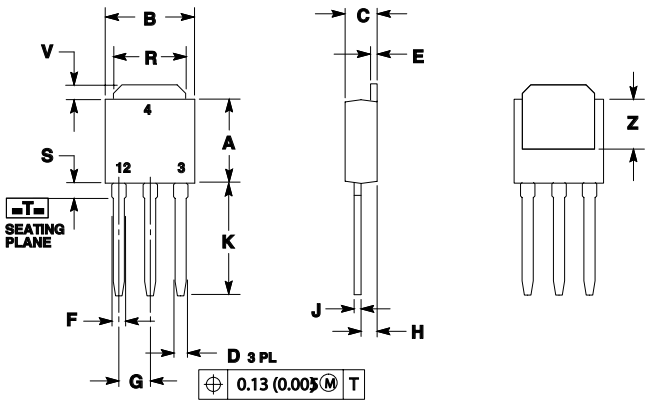
Dimensions

DPAK–3
CASE 369D–01
ISSUE B

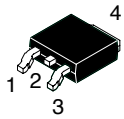


Dim	Inches		Millimeters	
	Min	Max	Min	Max
A	0.213	0.224	5.40	5.70
B	0.252	0.260	6.40	6.60
C	0.087	0.094	2.20	2.40
D	0.024	0.030	0.60	0.75
E	0.022	0.026	0.55	0.65
F	0.031	0.039	0.78	0.98
G	0.091		2.30	
H	0.046	0.050	1.18	1.28
J	0.019	0.023	0.49	0.59
K	0.291	0.315	7.40	8.00
R	0.209	0.217	5.30	5.50
S	0.063		1.60	
V	0.053	0.065	1.35	1.65
Z	0.150		3.80	

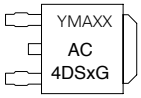
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

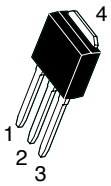
STYLE 6:
PIN 1. MT1
2. MT2
3. GATE
4. MT2

Part Marking System

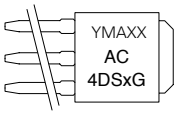


DPAK
CASE 369C
STYLE 6





DPAK–3
CASE 369D
STYLE 6



AC4DCx	=Device Code
x	=M or N
Y	=Year
M	=Month
A	=Assembly Site
XX	=Lot Serial Code
G	=Pb-Free Package

Pin Assignment	
1	Main Terminal 1
2	Main Terminal 2
3	Gate
4	Main Terminal 2

Ordering Information

Device	Package Type	Package	Shipping
MAC4DSM–001	DPAK–3	369D	4000 Unit/Box
MAC4DSM–001G	DPAK–3 (Pb–Free)	369D	4000 Unit/Box
MAC4DSMT4	DPAK–3	369C	2500 / Tape & Reel
MAC4DSMT4G	DPAK–3 (Pb–Free)	369C	2500 / Tape & Reel
MAC4DSN–001	DPAK–3	369D	4000 Unit/Box
MAC4DSN–001G	DPAK–3 (Pb–Free)	369D	4000 Unit/Box
MAC4DSNT4	DPAK–3	369C	2500 / Tape & Reel

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MAC4DSM-1G MAC4DSMT4G MAC4DSN-1G MAC4DSNT4G